

MBT3906DW1, SMBT3906DW1

Dual General Purpose Transistor

The MBT3906DW1 device is a spin-off of our popular SOT-23/SOT-323 three-leaded device. It is designed for general purpose amplifier applications and is housed in the SOT-363 six-leaded surface mount package. By putting two discrete devices in one package, this device is ideal for low-power surface mount applications where board space is at a premium.

Features

- h_{FE} , 100–300
- Low $V_{CE(sat)}$, ≤ 0.4 V
- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- Available in 8 mm, 7-inch/3,000 Unit Tape and Reel
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V_{CEO}	–40	Vdc
Collector–Base Voltage	V_{CBO}	–40	Vdc
Emitter–Base Voltage	V_{EBO}	–5.0	Vdc
Collector Current – Continuous	I_C	–200	mAdc
Electrostatic Discharge	ESD	HBM Class 2 MM Class B	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Package Dissipation (Note 1) $T_A = 25^\circ\text{C}$	P_D	150	mW
Thermal Resistance, Junction-to–Ambient	$R_{\theta JA}$	833	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature Range	T_J, T_{stg}	–55 to +150	$^\circ\text{C}$

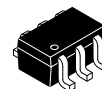
1. Device mounted on FR4 glass epoxy printed circuit board using the minimum recommended footprint.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

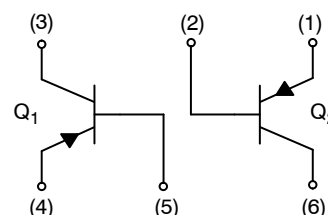


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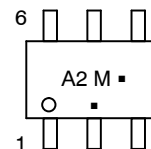
<http://onsemi.com>



SOT-363/SC-88
CASE 419B
STYLE 1



MARKING DIAGRAM



A2 = Device Code
M = Date Code
▪ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping†
MBT3906DW1T1G	SOT-363 (Pb-Free)	3,000 / Tape & Reel
MBT3906DW1T2G	SOT-363 (Pb-Free)	3,000 / Tape & Reel
SMBT3906DW1T1G	SOT-363 (Pb-Free)	3,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector – Emitter Breakdown Voltage (Note 2)	V _{(BR)CEO}	–40	–	Vdc
Collector – Base Breakdown Voltage	V _{(BR)CBO}	–40	–	Vdc
Emitter – Base Breakdown Voltage	V _{(BR)EBO}	–5.0	–	Vdc
Base Cutoff Current	I _{BL}	–	–50	nAdc
Collector Cutoff Current	I _{CEX}	–	–50	nAdc

ON CHARACTERISTICS (Note 2)

DC Current Gain (I _C = –0.1 mAdc, V _{CE} = –1.0 Vdc) (I _C = –1.0 mAdc, V _{CE} = –1.0 Vdc) (I _C = –10 mAdc, V _{CE} = –1.0 Vdc) (I _C = –50 mAdc, V _{CE} = –1.0 Vdc) (I _C = –100 mAdc, V _{CE} = –1.0 Vdc)	h _{FE}	60 80 100 60 30	– – 300 – –	–
Collector – Emitter Saturation Voltage (I _C = –10 mAdc, I _B = –1.0 mAdc) (I _C = –50 mAdc, I _B = –5.0 mAdc)	V _{CE(sat)}	– –	–0.25 –0.4	Vdc
Base – Emitter Saturation Voltage (I _C = –10 mAdc, I _B = –1.0 mAdc) (I _C = –50 mAdc, I _B = –5.0 mAdc)	V _{BE(sat)}	–0.65 –	–0.85 –0.95	Vdc

SMALL-SIGNAL CHARACTERISTICS

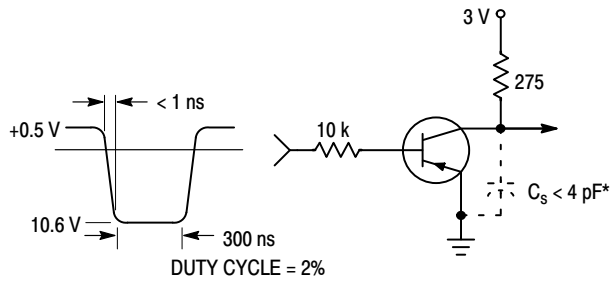
Current – Gain – Bandwidth Product	f _T	250	–	MHz
Output Capacitance	C _{obo}	–	4.5	pF
Input Capacitance	C _{ibo}	–	10.0	pF
Input Impedance (V _{CE} = –10 Vdc, I _C = –1.0 mAdc, f = 1.0 kHz)	h _{ie}	2.0	12	kΩ
Voltage Feedback Ratio (V _{CE} = –10 Vdc, I _C = –1.0 mAdc, f = 1.0 kHz)	h _{re}	0.1	10	X 10 ^{–4}
Small – Signal Current Gain (V _{CE} = –10 Vdc, I _C = –1.0 mAdc, f = 1.0 kHz)	h _{fe}	100	400	–
Output Admittance (V _{CE} = –10 Vdc, I _C = –1.0 mAdc, f = 1.0 kHz)	h _{oe}	3.0	60	μmhos
Noise Figure (V _{CE} = –5.0 Vdc, I _C = –100 μAdc, R _S = 1.0 k Ω, f = 1.0 kHz)	NF	–	4.0	dB

SWITCHING CHARACTERISTICS

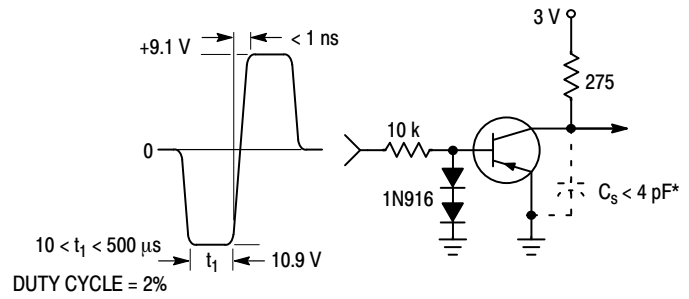
Delay Time	(V _{CC} = –3.0 Vdc, V _{BE} = 0.5 Vdc)	t _d	–	35	ns
Rise Time	(I _C = –10 mAdc, I _{B1} = –1.0 mAdc)	t _r	–	35	
Storage Time	(V _{CC} = –3.0 Vdc, I _C = –10 mAdc)	t _s	–	225	ns
Fall Time	(I _{B1} = I _{B2} = –1.0 mAdc)	t _f	–	75	

2. Pulse Test: Pulse Width ≤ 300 μs; Duty Cycle ≤ 2.0%.

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**Figure 1. Delay and Rise Time
Equivalent Test Circuit**



**Figure 2. Storage and Fall Time
Equivalent Test Circuit**

* Total shunt capacitance of test jig and connectors

TYPICAL TRANSIENT CHARACTERISTICS

— $T_J = 25^\circ\text{C}$
 - - $T_J = 125^\circ\text{C}$

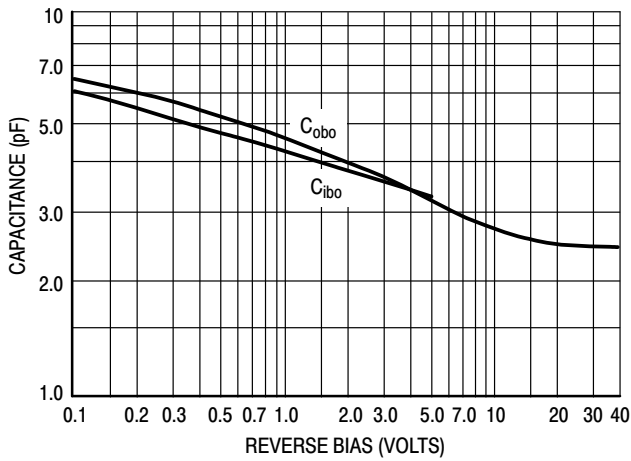


Figure 3. Capacitance

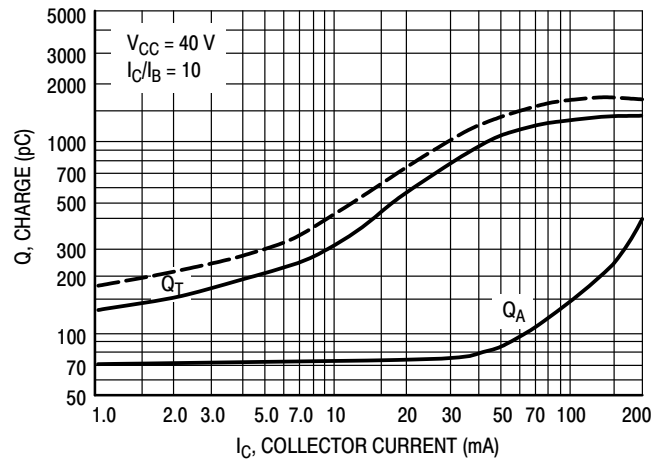


Figure 4. Charge Data

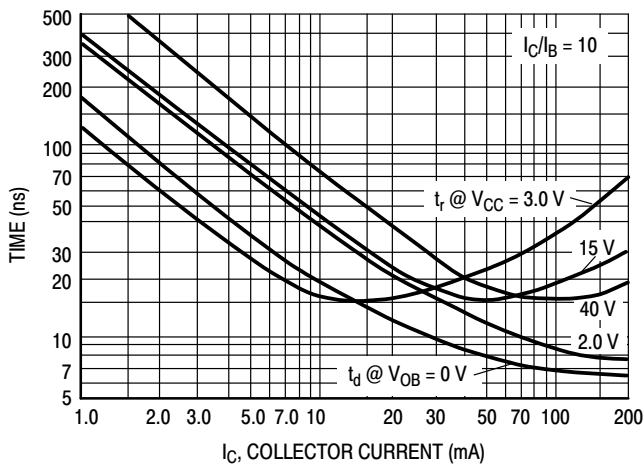


Figure 5. Turn-On Time

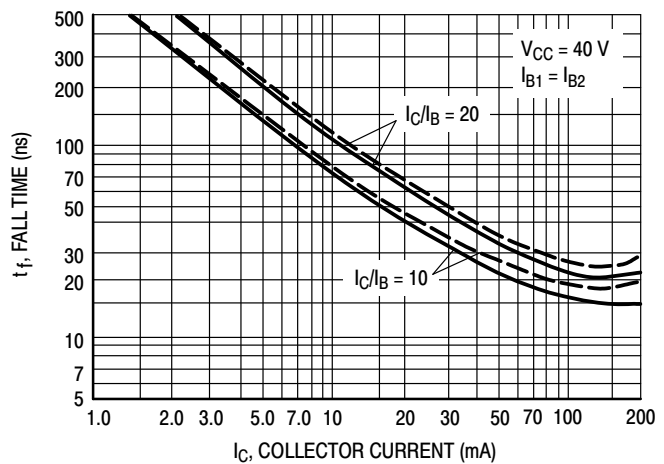


Figure 6. Fall Time

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TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE VARIATIONS

($V_{CE} = -5.0$ Vdc, $T_A = 25^\circ\text{C}$, Bandwidth = 1.0 Hz)

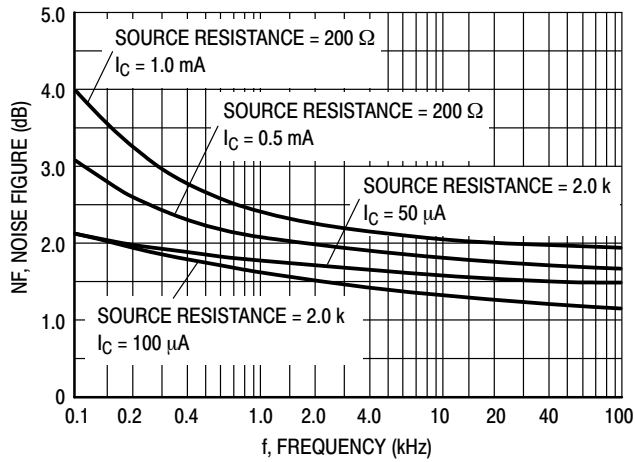


Figure 7.

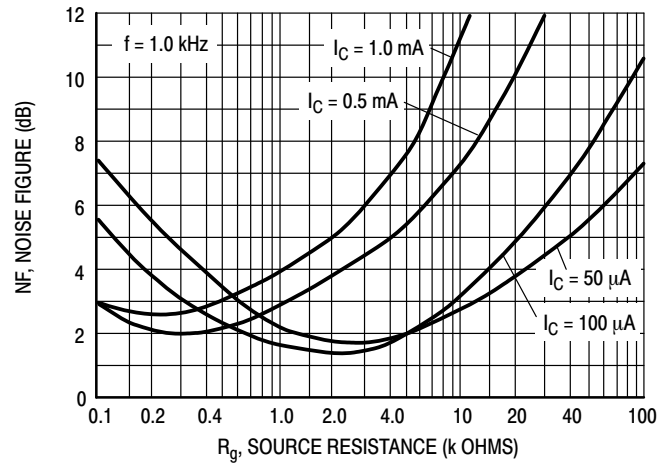


Figure 8.

h PARAMETERS

($V_{CE} = -10$ Vdc, $f = 1.0$ kHz, $T_A = 25^\circ\text{C}$)

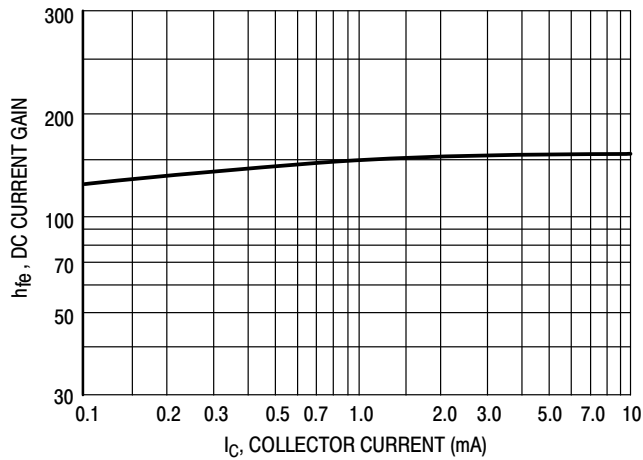


Figure 9. Current Gain

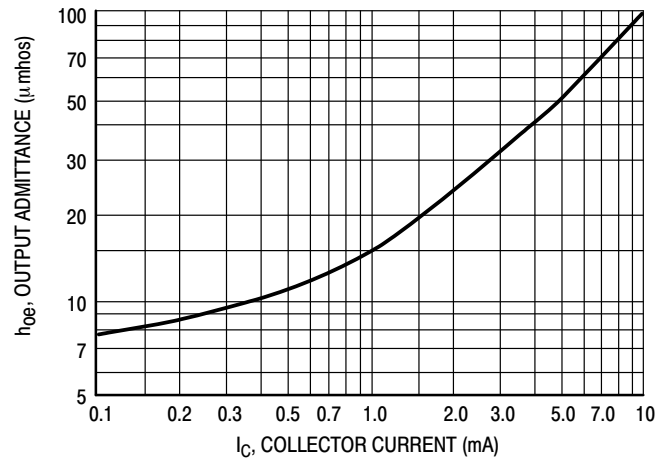


Figure 10. Output Admittance

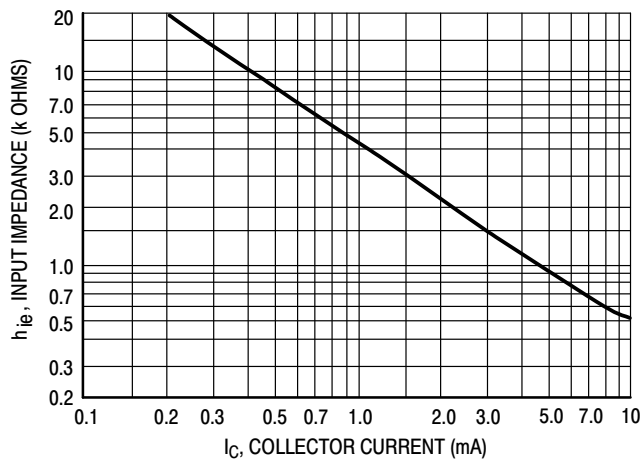


Figure 11. Input Impedance

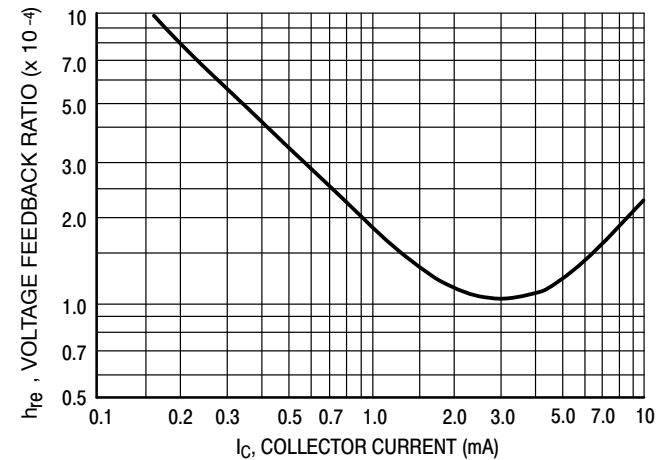


Figure 12. Voltage Feedback Ratio

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TYPICAL STATIC CHARACTERISTICS

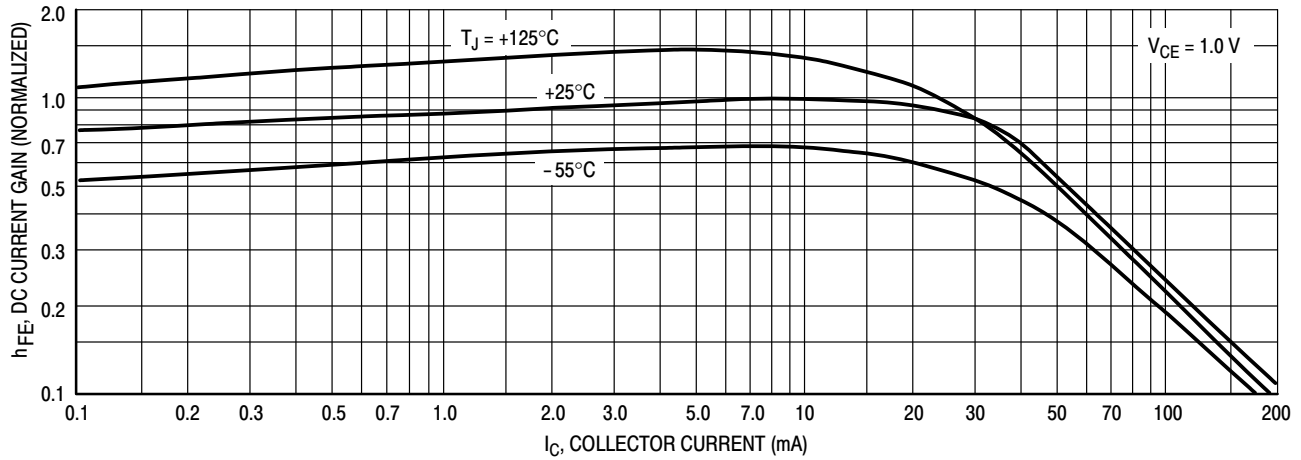


Figure 13. DC Current Gain

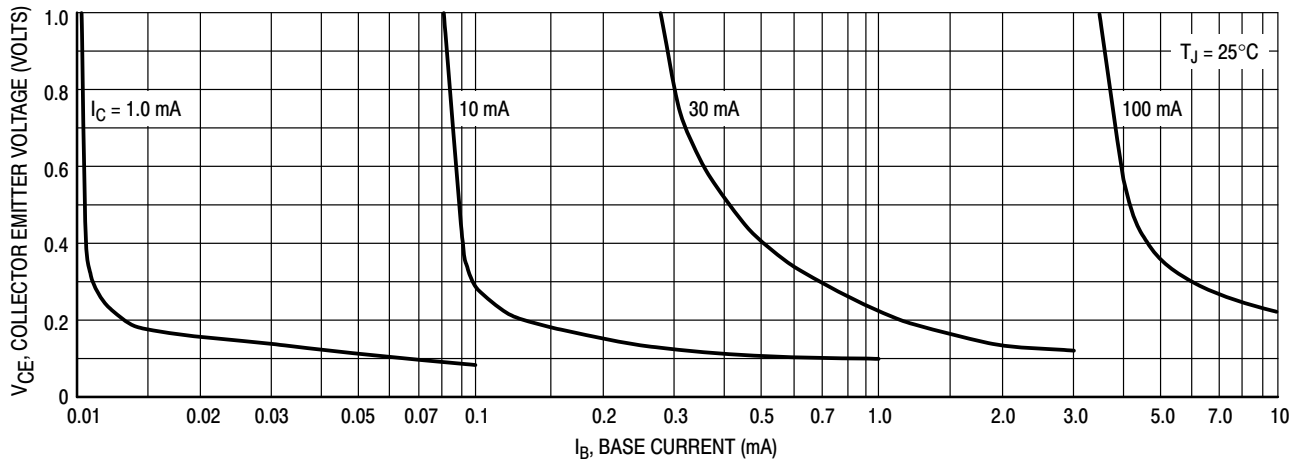


Figure 14. Collector Saturation Region

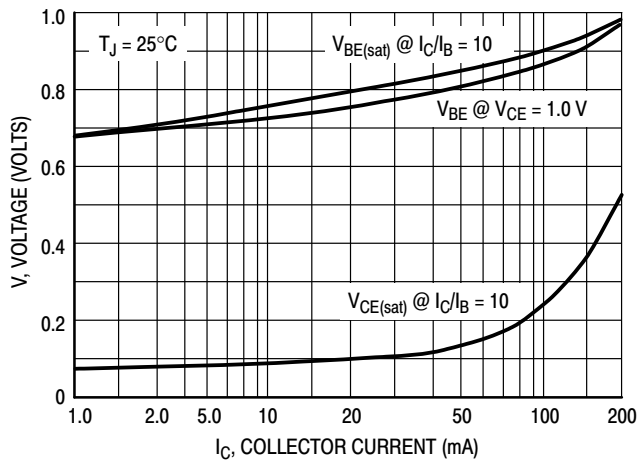


Figure 15. "ON" Voltages

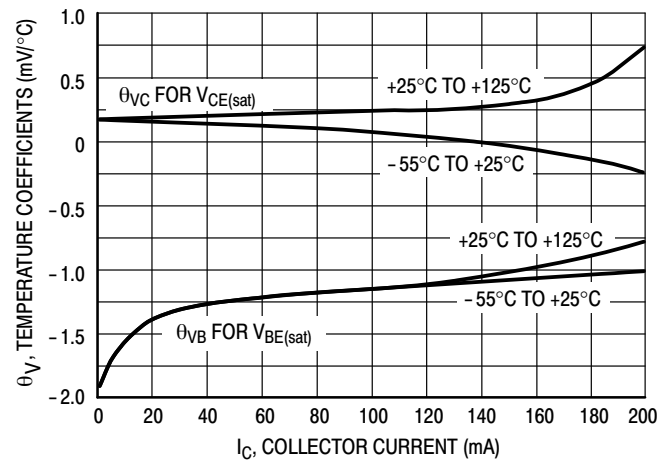
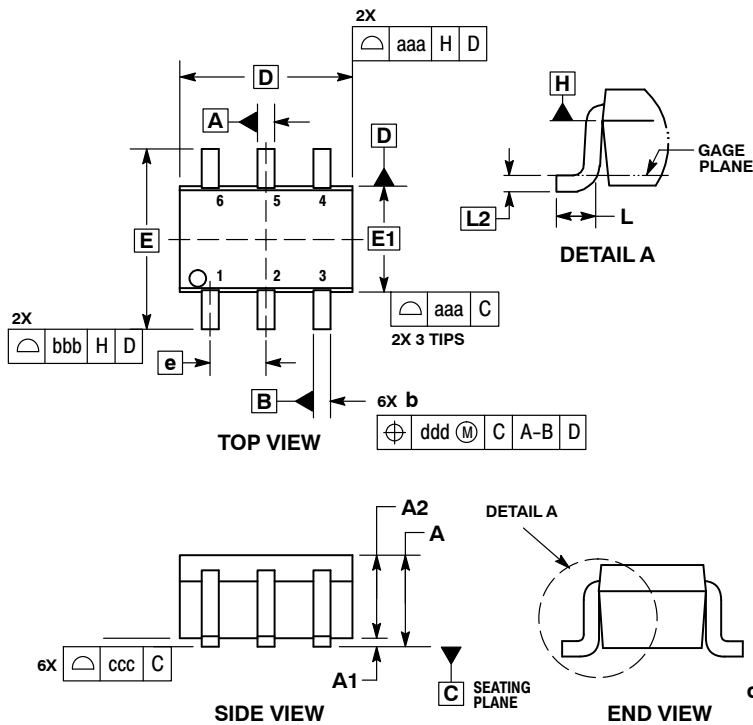


Figure 16. Temperature Coefficients

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PACKAGE DIMENSIONS

SC-88/SC70-6/SOT-363
CASE 419B-02
ISSUE Y



NOTES:

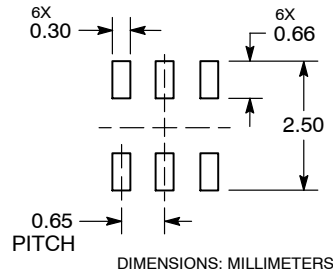
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.20 PER END.
4. DIMENSIONS D AND E1 AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY AND DATUM H.
5. DATUMS A AND B ARE DETERMINED AT DATUM H.
6. DIMENSIONS b AND c APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.08 AND 0.15 FROM THE TIP.
7. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 TOTAL IN EXCESS OF DIMENSION b AT MAXIMUM MATERIAL CONDITION. THE DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OF THE FOOT.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	---	---	1.10	---	---	0.043
A1	0.00	---	0.10	0.000	---	0.004
A2	0.70	0.90	1.00	0.027	0.035	0.039
b	0.15	0.20	0.25	0.006	0.008	0.010
C	0.08	0.15	0.22	0.003	0.006	0.009
D	1.80	2.00	2.20	0.070	0.078	0.086
E	2.00	2.10	2.20	0.078	0.082	0.086
E1	1.15	1.25	1.35	0.045	0.049	0.053
e	0.65 BSC			0.026 BSC		
L	0.26	0.36	0.46	0.010	0.014	0.018
L2	0.15 BSC			0.006 BSC		
aaa	0.15			0.006		
bbb	0.30			0.012		
ccc	0.10			0.004		
ddd	0.10			0.004		

STYLE 1:

- PIN 1. EMITTER 2
- BASE 2
- COLLECTOR 1
- EMITTER 1
- BASE 1
- COLLECTOR 2

RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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MBT3906DW1T1/D

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